NSN 5962-01-388-2929

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Next assembly: 8515198-910 used o (sys): 8515143-910
Features Provided:
Electrostatic sensitive and tested to mil-std-883 and burn in and programmed
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
C-2a mil-m-38510
Product Name:
16-input 8-output and-or invert logic array
Voltage Rating And Type Per Characteristic:
-3.0 volts absolute input and 7.0 volts absolute input
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
20 leadless
Specification Data:
67268-5962-88713 government standard
Departure From Cited Designator:
Programmed per: tt8517302-111
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0